74LVC1G00

Single 2-input NAND gate

Rev. 12 — 6 February 2019

Product data sheet

1. General description

The 74LVC1G00 provides the single 2-input NAND function.

Input can be driven from either $3.3\ V$ or $5\ V$ devices. These features allow the use of these devices in a mixed $3.3\ V$ and $5\ V$ environment.

Schmitt trigger action at all inputs makes the circuit tolerant for slower input rise and fall time.

This device is fully specified for partial power-down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

2. Features and benefits

- Wide supply voltage range from 1.65 V to 5.5 V
- · High noise immunity
- Complies with JEDEC standard:
 - JESD8-7 (1.65 V to 1.95 V)
 - JESD8-5 (2.3 V to 2.7 V)
 - JESD8-B/JESD36 (2.7 V to 3.6 V)
- ±24 mA output drive (V_{CC} = 3.0 V)
- CMOS low power consumption
- Latch-up performance exceeds 250 mA
- Direct interface with TTL levels
- Inputs accept voltages up to 5 V
- Multiple package options
- ESD protection:
 - HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V
- Specified from -40 °C to +85 °C and -40 °C to +125 °C



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3. Ordering information

Table 1. Ordering information

Type number	Package	Package						
	Temperature range	Name	Description	Version				
74LVC1G00GW	-40 °C to +125 °C	TSSOP5	plastic thin shrink small outline package; 5 leads; body width 1.25 mm	SOT353-1				
74LVC1G00GV	-40 °C to +125 °C	SC-74A	plastic surface-mounted package; 5 leads	SOT753				
74LVC1G00GM	-40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 x 1.45 x 0.5 mm	SOT886				
74LVC1G00GF	-40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 x 1 x 0.5 mm	SOT891				
74LVC1G00GN	-40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 0.9 x 1.0 x 0.35 mm	SOT1115				
74LVC1G00GS	-40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 1.0 x 1.0 x 0.35 mm	SOT1202				
74LVC1G00GX	-40 °C to +125 °C	X2SON5	X2SON5: plastic thermal enhanced extremely thin small outline package; no leads; 5 terminals; body 0.8 x 0.8 x 0.35 mm	SOT1226				

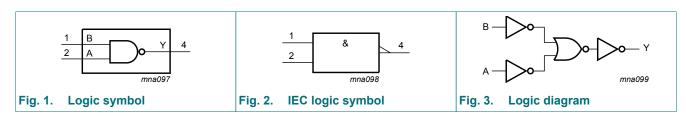
4. Marking

Table 2. Marking codes

Type number	Marking[1]
74LVC1G00GW	VA
74LVC1G00GV	V00
74LVC1G00GM	VA
74LVC1G00GF	VA
74LVC1G00GN	VA
74LVC1G00GS	VA
74LVC1G00GX	VA

^[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

5. Functional diagram

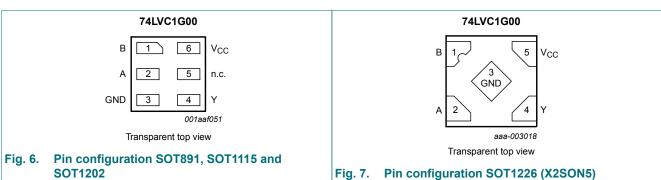


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6. Pinning information

6.1. Pinning





6.2. Pin description

Table 3. Pin description

Symbol	Pin	Pin		
	TSSOP5 and X2SON5	XSON6		
В	1	1	data input	
A	2	2	data input	
GND	3	3	ground (0 V)	
Υ	4	4	data output	
n.c.	-	5	not connected	
V _{CC}	5	6	supply voltage	

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7. Functional description

Table 4. Function table

 $H = HIGH \ voltage \ level; \ L = LOW \ voltage \ level.$

Inputs	Outputs	
A	В	Υ
L	L	Н
L	Н	Н
Н	L	Н
Н	Н	L

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CC}	supply voltage			-0.5	+6.5	V
I _{IK}	input clamping current	V _I < 0 V		-50	-	mA
VI	input voltage		[1]	-0.5	+6.5	V
I _{OK}	output clamping current	$V_O > V_{CC}$ or $V_O < 0$ V		-	±50	mA
V _O	output voltage	Active mode	[1][2]	-0.5	V _{CC} + 0.5	V
		Power-down mode	[1][2]	-0.5	+6.5	V
I _O	output current	$V_O = 0 V \text{ to } V_{CC}$		-	±50	mA
I _{CC}	supply current			-	+100	mA
I _{GND}	ground current			-100	-	mA
P _{tot}	total power dissipation	T _{amb} = -40 °C to +125 °C	[3]	-	250	mW
T _{stg}	storage temperature			-65	+150	°C

^[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

9. Recommended operating conditions

Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{CC}	supply voltage		1.65	-	5.5	V
VI	input voltage		0	-	5.5	V
Vo	output voltage	Active mode	0	-	V _{CC}	V
		V _{CC} = 0 V; Power-down mode	0	-	5.5	V
T _{amb}	ambient temperature		-40	-	+125	°C
Δt/ΔV	input transition rise and fall rate	V _{CC} = 1.65 V to 2.7 V	-	-	20	ns/V
		V _{CC} = 2.7 V to 5.5 V	-	-	10	ns/V

^[2] When $V_{CC} = 0 \text{ V}$ (Power-down mode), the output voltage can be 5.5 V in normal operation.

^[3] For TSSOP5 and SC-74A packages: above 87.5 °C the value of P_{tot} derates linearly with 4.0 mW/K. For XSON6 and X2SON5 packages: above 118 °C the value of P_{tot} derates linearly with 7.8 mW/K.

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10. Static characteristics

Table 7. Static characteristics

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	-40 °C to			-40 °C to +125 °C		Unit	
			Min	Typ[1]	Max	Min Max			
V _{IH}	HIGH-level	V _{CC} = 1.65 V to 1.95 V	0.65V _{CC}	-	-	0.65V _{CC}	-	V	
	input voltage	V _{CC} = 2.3 V to 2.7 V	1.7	-	-	1.7	-	V	
		V _{CC} = 2.7 V to 3.6 V	2.0	-	-	2.0	-	V	
		V _{CC} = 4.5 V to 5.5 V	0.7V _{CC}	-	-	0.7V _{CC}	-	V	
V _{IL}	LOW-level	V _{CC} = 1.65 V to 1.95 V	-	-	0.35V _{CC}	-	0.35V _{CC}	V	
	input voltage	V _{CC} = 2.3 V to 2.7 V	-	-	0.7	-	0.7	V	
		V _{CC} = 2.7 V to 3.6 V	-	-	0.8	-	0.8	V	
		V _{CC} = 4.5 V to 5.5 V	-	-	0.3V _{CC}	-	0.3V _{CC}	V	
V _{OH}	HIGH-level	V _I = V _{IH} or V _{IL}							
	output voltage	I _O = -100 μA; V _{CC} = 1.65 V to 5.5 V	V _{CC} - 0.1	-	-	V _{CC} - 0.1	-	V	
		I _O = -4 mA; V _{CC} = 1.65 V	1.2	-	-	0.95	-	V	
		I_{O} = -8 mA; V_{CC} = 2.3 V	1.9	-	-	1.7	-	V	
		I_{O} = -12 mA; V_{CC} = 2.7 V	2.2	-	-	1.9	-	V	
		I _O = -24 mA; V _{CC} = 3.0 V	2.3	-	-	2.0	-	V	
		I_{O} = -32 mA; V_{CC} = 4.5 V	3.8	-	-	3.4	-	V	
V _{OL}	LOW-level output voltage	V _I = V _{IH} or V _{IL}							
		I _O = 100 μA; V _{CC} = 1.65 V to 5.5 V	-	-	0.1	-	0.1	V	
		I _O = 4 mA; V _{CC} = 1.65 V	-	-	0.45	-	0.70	V	
		I _O = 8 mA; V _{CC} = 2.3 V	-	-	0.3	-	0.45	V	
		I _O = 12 mA; V _{CC} = 2.7 V	-	-	0.4	-	0.60	V	
		I _O = 24 mA; V _{CC} = 3.0 V	-	-	0.55	-	0.80	V	
		I _O = 32 mA; V _{CC} = 4.5 V	-	-	0.55	-	0.80	V	
I _I	input leakage current	V _I = 5.5 V or GND; V _{CC} = 0 V to 5.5 V	-	±0.1	±1	-	±1	μΑ	
I _{OFF}	power-off leakage current	$V_{CC} = 0 \text{ V}; V_1 \text{ or } V_0 = 5.5 \text{ V}$	-	±0.1	±2	-	±2	μA	
I _{CC}	supply current	V _I = 5.5 V or GND; I _O = 0 A; V _{CC} = 1.65 V to 5.5 V	-	0.1	4	-	4	μΑ	
ΔI _{CC}	additional supply current	V_{CC} = 2.3 V to 5.5 V; V_{I} = V_{CC} - 0.6 V; I_{O} = 0 A; per pin	-	5	500	-	500	μΑ	
C _I	input capacitance	V_{CC} = 3.3 V; V_I = GND to V_{CC}	-	5	-	-	-	pF	

^[1] All typical values are measured at V_{CC} = 3.3 V and T_{amb} = 25 °C.

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11. Dynamic characteristics

Table 8. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 9.

Symbol	Parameter	Conditions	-40 °C to +85 °C			-40 °C to +125 °C		Unit
			Min	Typ[1]	Max	Min	Max	
t _{pd}	propagation delay	A, B to Y; see <u>Fig. 8</u> [2]						
		V _{CC} = 1.65 V to 1.95 V	1.0	3.3	8.0	1.0	10.5	ns
		V _{CC} = 2.3 V to 2.7 V	0.5	2.2	5.5	0.5	7.0	ns
		V _{CC} = 2.7 V	0.5	2.6	5.8	0.5	7.5	ns
		V _{CC} = 3.0 V to 3.6 V	0.5	2.2	4.7	0.5	6.0	ns
		V _{CC} = 4.5 V to 5.5 V	0.5	1.8	4.0	0.5	5.5	ns
C _{PD}	power dissipation capacitance	$V_I = GND \text{ to } V_{CC};$ [3] $V_{CC} = 3.3 \text{ V}$	-	14	-	-	-	pF

- Typical values are measured at T_{amb} = 25 °C and V_{CC} = 1.8 V, 2.5 V, 2.7 V, 3.3 V and 5.0 V respectively.
- t_{pd} is the same as t_{PLH} and t_{PHL} . C_{PD} is used to determine the dynamic power dissipation (P_D in μ W). $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum (C_L \times V_{CC}^2 \times f_o)$ where:

 f_i = input frequency in MHz;

 f_0 = output frequency in MHz;

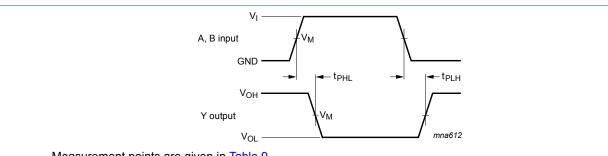
C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\sum (C_L \times V_{CC}^2 \times f_0) = \text{sum of outputs.}$

11.1. Waveform and test circuit



Measurement points are given in Table 9.

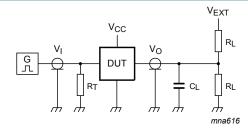
V_{OL} and V_{OH} are typical output voltage levels that occur with the output.

The input (A and B) to output (Y) propagation delay times Fig. 8.

Table 9. Measurement points

Supply voltage	Input	Output
V _{CC}	V _M	V _M
1.65 V to 1.95 V	0.5V _{CC}	0.5V _{CC}
2.3 V to 2.7 V	0.5V _{CC}	0.5V _{CC}
2.7 V	1.5 V	1.5 V
3.0 V to 3.6 V	1.5 V	1.5 V
4.5 V to 5.5 V	0.5V _{CC}	0.5V _{CC}

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Test data is given in Table 10.

Definitions for test circuit:

 R_L = Load resistance.

 C_L = Load capacitance including jig and probe capacitance.

 R_T = Termination resistance should be equal to the output impedance Z_0 of the pulse generator.

 V_{EXT} = External voltage for measuring switching times.

Fig. 9. Test circuit for measuring switching times

Table 10. Test data

Supply voltage	Input	Input		Load		
V _{CC}	VI	$t_r = t_f$	CL	R _L	t _{PLH} , t _{PHL}	
1.65 V to 1.95 V	V _{CC}	≤ 2.0 ns	30 pF	1 kΩ	open	
2.3 V to 2.7 V	V _{CC}	≤ 2.0 ns	30 pF	500 Ω	open	
2.7 V	2.7 V	≤ 2.5 ns	50 pF	500 Ω	open	
3.0 V to 3.6 V	2.7 V	≤ 2.5 ns	50 pF	500 Ω	open	
4.5 V to 5.5 V	V _{CC}	≤ 2.5 ns	50 pF	500 Ω	open	

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12. Package outline

TSSOP5: plastic thin shrink small outline package; 5 leads; body width 1.25 mm SOT353-1 = v M A ⊕ w M detail X 3 mm scale **DIMENSIONS (mm are the original dimensions)** ΗE A_2 Α3 $D^{(1)}$ $E^{(1)}$ e₁ L $Z^{(1)}$ UNIT θ Lp max 0.30 0.25 1.35 0.60 1.1 mm 0.15 0.65 1.3 0.425 0.3 0.1 0.1

Note

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

OUTLINE		REFERENCES		REFERENCES		EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE		
SOT353-1		MO-203	SC-88A		-00-09-01 03-02-19		

Fig. 10. Package outline SOT353-1 (TSSOP5)

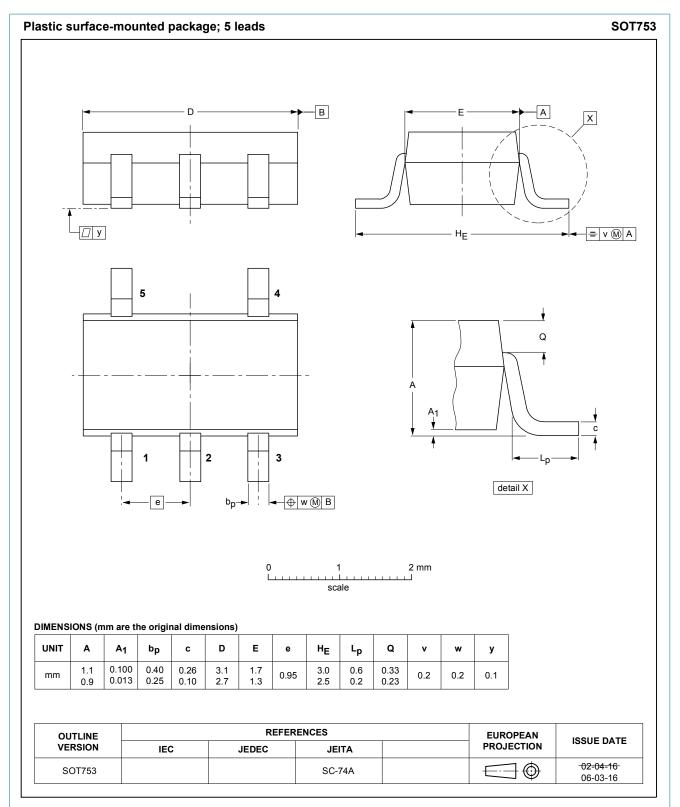


Fig. 11. Package outline SOT753 (SC-74A)

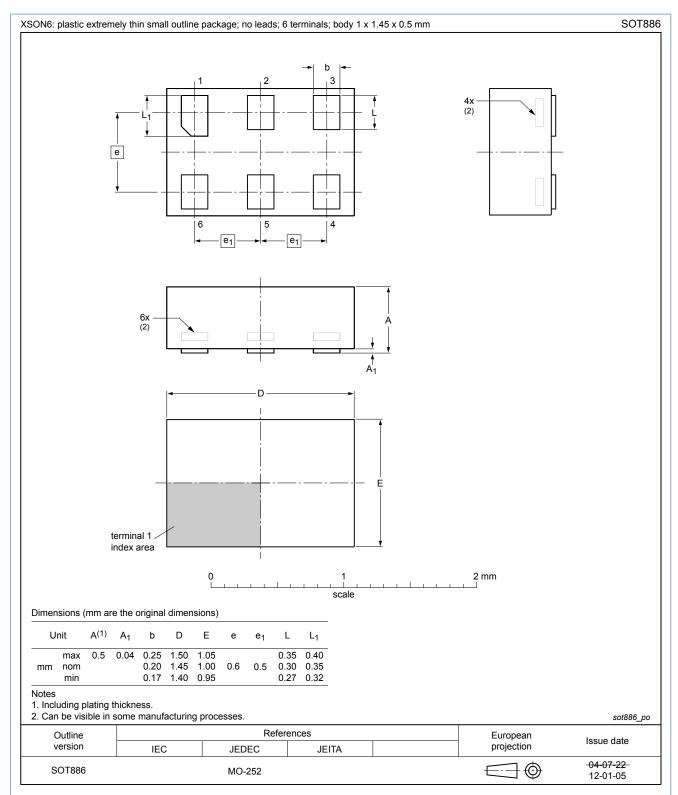


Fig. 12. Package outline SOT886 (XSON6)

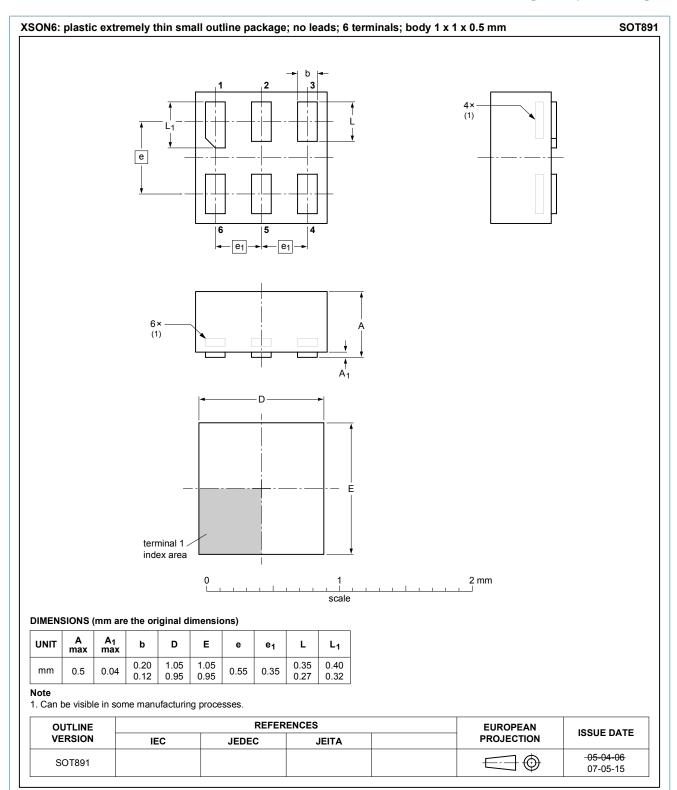


Fig. 13. Package outline SOT891 (XSON6)

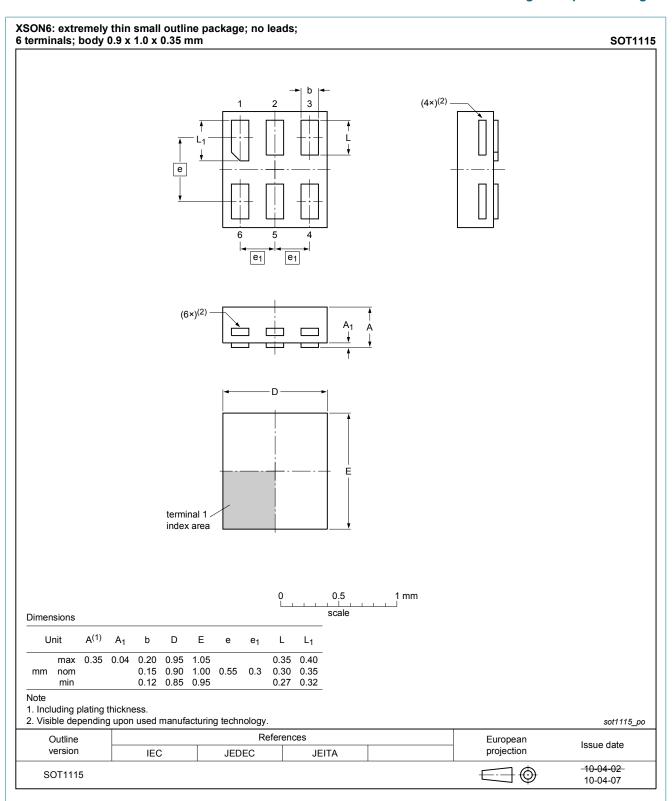


Fig. 14. Package outline SOT1115 (XSON6)

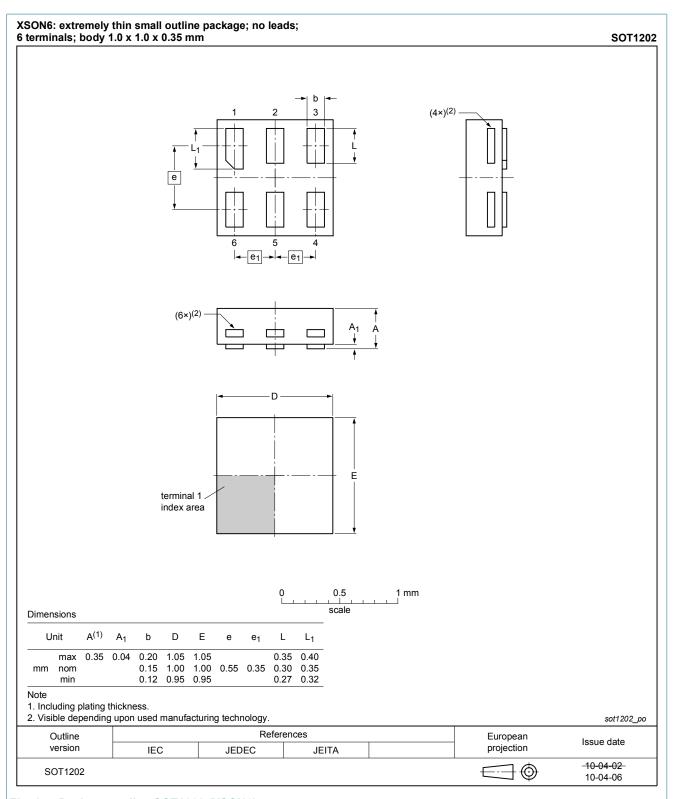


Fig. 15. Package outline SOT1202 (XSON6)

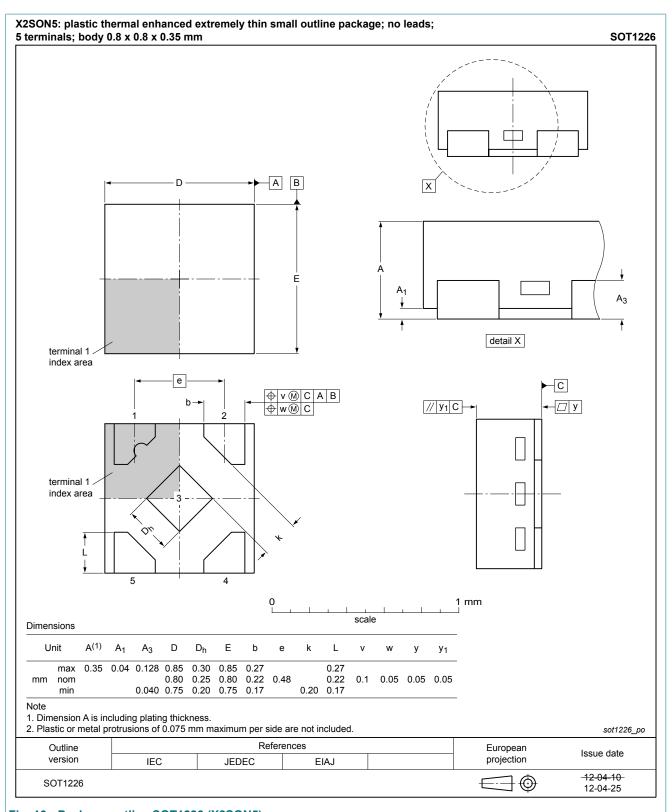


Fig. 16. Package outline SOT1226 (X2SON5)

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13. Abbreviations

Table 11. Abbreviations

Acronym	Description	
CMOS Complementary Metal Oxide Semiconductor		
DUT	DUT Device Under Test	
ESD	ElectroStatic Discharge	
HBM	Human Body Model	
MM	Machine Model	
TTL	Transistor-Transistor Logic	

14. Revision history

Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74LVC1G00 v.12	20190206	Product data sheet	-	74LVC1G00 v.11
Modifications:	Nexperia.	of this data sheet has been rede nave been adapted to the new o		
74LVC1G00 v.11	20161129	Product data sheet	-	74LVC1G00 v.10
Modifications:	• <u>Table 7</u> : The	maximum limits for leakage cu	rrent and supply curr	ent have changed.
74LVC1G00 v.10	20120702	Product data sheet	-	74LVC1G00 v.9
Modifications:	 Added type number 74LVC1G00GX (SOT1226) Package outline drawing of SOT886 (Fig. 12) modified. 			
74LVC1G00 v.9	20111207	Product data sheet	-	74LVC1G00 v.8
Modifications:	 Legal pages 	updated.		
74LVC1G00 v.8	20101020	Product data sheet	-	74LVC1G00 v.7
74LVC1G00 v.7	20070717	Product data sheet	-	74LVC1G00 v.6
74LVC1G00 v.6	20060915	Product data sheet	-	74LVC1G00 v.5
74LVC1G00 v.5	20040907	Product specification	-	74LVC1G00 v.4
74LVC1G00 v.4	20021115	Product specification	-	74LVC1G00 v.3
74LVC1G00 v.3	20020515	Product specification	-	74LVC1G00 v.2
74LVC1G00 v.2	20010405	Product specification	-	74LVC1G00 v.1
74LVC1G00 v.1	20001108	Product specification	-	-

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15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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